

# 标准&定制开关连接器产品制造商 DONG GUAN XI BANG ELECTRONICS CO., LTD.

### 4 PIN SSOP PHOTOTRANSISTOR PHOTOCOUPLER **EL3H7L-G Series**

**Preliminary** 

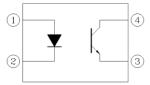




#### Features:

- · Halogens free (Br <900 ppm ,Cl <900 ppm , Br+Cl < 1500 ppm)
- · Current transfer ratio (CTR: 50~600% at IF =0.1mA, VCE =5V)
- High isolation voltage between input and output (Viso=3750 V rms)
- Compact 4 Pin SSOP with a 2.0 mm profile
- Compliance with EU REACH
- Pb free and RoHS compliant.
- UL and cUL approved(No. E214129)
- VDE approved (No. 132249)
- SEMKO approved
- NEMKO approved
- DEMKO approved
- FIMKO approved

### **Schematic**



#### Pin Configuration

- 1. Anode
- 2. Cathode
- 3. Emitter
- 4. Collector

This is a preliminary specification intended for design purposes and subject to change without prior notice.

#### **Description**

The EL3H7L-G series devices consist of an infrared emitting diode, optically coupled to a phototransistor detector encapsulated with green compound.

They are packaged in a 4-pin small outline SMD package.

#### **Applications**

- DC-DC Converters
- Programmable controllers
- Telecommunication equipments
- Signal transmission between circuits of different potentials and impedances

### Absolute Maximum Ratings (Ta=25°℃)

	Parameter	Symbol	Rating	Unit
	Forward current	I <sub>F</sub>	50	mA
	Peak forward current (1us, pulse)	I <sub>FP</sub>	1	А
Innut	Reverse voltage	V <sub>R</sub>	6	V
Input	Power dissipation	<b>D</b>	70	mW
	Derating factor (above $T_a = 90^{\circ}C$ )	P <sub>D</sub> —	2.0	mW/°C
	Power dissipation Derating factor (above T <sub>a</sub> = 70°C)	P <sub>C</sub> —	150	mW
			3.1	mW/°C
Output	Collector current	Ic	50	mA
	Collector-Emitter voltage	V <sub>CEO</sub>	80	V
	Emitter-Collector voltage	V <sub>ECO</sub>	7	V
Total Power	er Dissipation	Ртот	200	mW
Isolation \	/oltage*1	V <sub>ISO</sub>	3750	Vrms
Operating temperature		T <sub>OPR</sub>	-55 ~ +110	°C
Storage temperature		T <sub>STG</sub>	-55 ~ +125	°C
Soldering Temperature*2		T <sub>SOL</sub>	260	°C

#### Notes:

 $<sup>^*1</sup>$  AC for 1 minute, R.H.=  $40 \sim 60\%$  R.H. In this test, pins 1, 2 are shorted together, and pins 3, 4 are shorted together.

<sup>\*2</sup> For 10 seconds

### Electro-Optical Characteristics (Ta=25°C unless specified otherwise)

Input

Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition
Forward voltage	V <sub>F</sub>	-	1.3	1.5	V	$I_F = 20 \text{mA}$
Reverse current	$I_R$	-	-	10	μΑ	V <sub>R</sub> = 6V
Input capacitance	Cin	-	30	250	pF	V = 0, f = 1kHz

Output

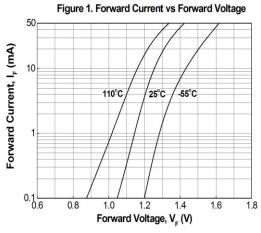
Parameter	Symbol	Min	Тур.	Max.	Unit	Condition
Collector-Emitter dark current	I <sub>CEO</sub>	-	-	100	nA	V <sub>CE</sub> = 20V, I <sub>F</sub> = 0mA
Collector-Emitter breakdown voltage	$BV_CEO$	80	-	-	V	I <sub>C</sub> = 0.1mA
Emitter-Collector breakdown voltage	$BV_{ECO}$	7	-	-	V	$I_E = 0.1 \text{mA}$

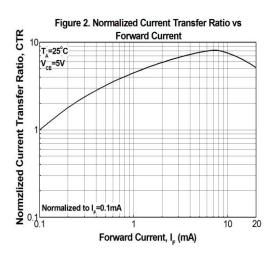
Transfer Characteristics (T<sub>a</sub>=25°C unless specified otherwise)

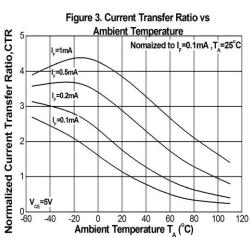
Parameter	Symbol	Min	Тур.	Max.	Unit	Condition
Current Transfer EL3H7L ratio	CTR	50	-	600	%	I <sub>F</sub> = 0.1mA ,V <sub>CE</sub> = 5V
Collector-Emitter saturation voltage	V <sub>CE(sat)</sub>	-	-	0.3	V	I <sub>F</sub> = 10mA ,I <sub>C</sub> = 1mA
Isolation resistance	R <sub>IO</sub>	5×10 <sup>10</sup>	-	-	Ω	V <sub>IO</sub> = 500Vdc, 40~60% R.H.
Floating capacitance	$C_{IO}$	-	0.3	1.0	pF	$V_{IO} = 0$ , $f = 1MHz$
Rise time	t <sub>r</sub>	-	8	18	μs	V <sub>CE</sub> = 2V, I <sub>C</sub> = 2mA,
Fall time	t <sub>f</sub>	-	12	18	μs	$R_L = 100\Omega$

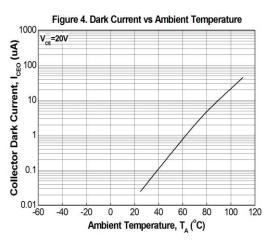
<sup>\*</sup> Typical values at T<sub>a</sub> = 25°C

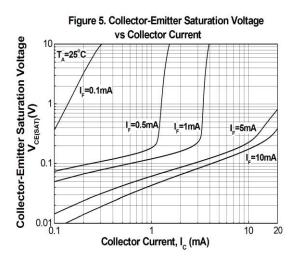
#### **Typical Electro-Optical Characteristics Curves**

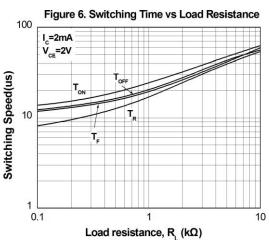












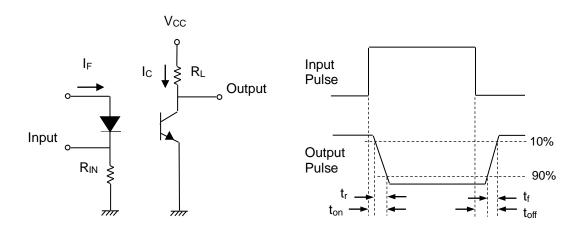


Figure 11. Switching Time Test Circuit & Waveforms

#### **Order Information**

#### **Part Number**

## EL3H7L(X)-VG

#### Note

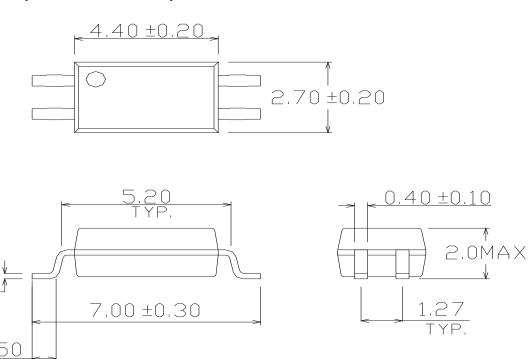
L = Operating at low current

X = Tape and reel option (TA, TB, EA, EB or none) V = VDE (optional)

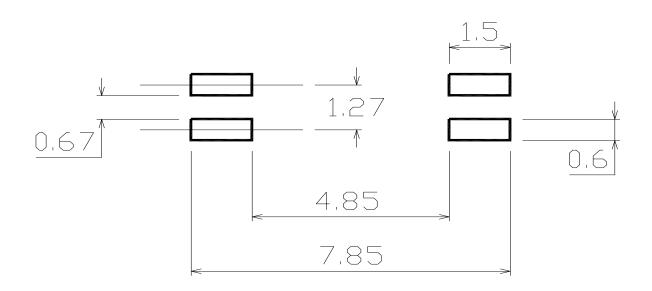
V = VDE (optional) G = Halogens free

Option	Description	Packing quantity
None	Standard SMD option	150 units per tube
-V	Standard SMD option + VDE	150 units per tube
(TA)	TA Tape & reel option	5000 units per reel
(TB)	TB Tape & reel option	5000 units per reel
(TA)-V	TA Tape & reel option + VDE	5000 units per reel
(TB)-V	TB Tape & reel option + VDE	5000 units per reel
(EA)	TA Tape & reel option	1000 units per reel
(EB)	TB Tape & reel option	1000 units per reel
(EA)-V	TA Tape & reel option + VDE	1000 units per reel
(EB)-V	TB Tape & reel option + VDE	1000 units per reel

### Package Dimension (Dimensions in mm)



### Recommended pad layout for surface mount leadform



### **Device Marking**



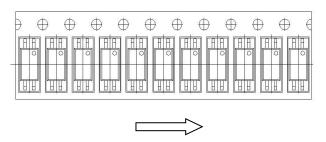
#### **Notes**

EL denotes XI BNANG 3H7L denotes Device Number Y denotes 1 digit Year code WW denotes 2 digit Week code V denotes VDE (optional)



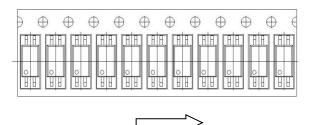
### **Tape & Reel Packing Specifications**

### **Option TA**



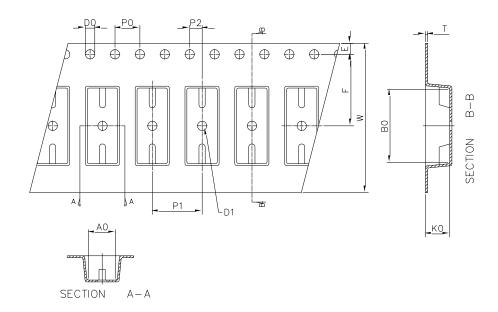
Direction of feed from reel

#### **Option TB**



Direction of feed from reel

#### **Tape dimesions**

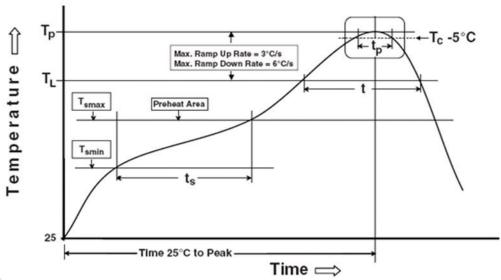


Dimension No.	A0	В0	D0	D1	E	F
Dimension (mm)	3.00 ± 0.10	7.45 ± 0.10	1.50 + 0.1/-0	1.50 ± 0.10	1.75± 0.10	5.50 ± 0.10
Dimension No.	Ро	P1	P2	t	W	K0
Dimension (mm)	4.00 ± 0.15		2.00 ± 0.10	$0.30 \pm 0.05$	12.1 ± 0.2	2.45 ± 0.1

#### **Precautions for Use**

#### 1. Soldering Condition

1.1 (A) Maximum Body Case Temperature Profile for evaluation of Reflow Profile



Note: Reference: IPC/JEDEC J-STD-020D

#### **Preheat**

Temperature min (T <sub>smin</sub> )	150 °C
Temperature max (T <sub>smax</sub> )	200°C
Time (T <sub>smin</sub> to T <sub>smax</sub> ) (t <sub>s</sub> )	60-120 seconds
Average ramp-up rate (T <sub>smax</sub> to T <sub>n</sub> )	3 °C/second max

#### Other

Liquidus Temperature (T∟)	217 °C
Time above Liquidus Temperature (t L)	60-100 sec
Peak Temperature (T <sub>P</sub> )	260°C
Time within 5 °C of Actual Peak Temperature: T <sub>P</sub> - 5°C	30 s
Ramp- Down Rate from Peak Temperature	6°C /second max.
Time 25°C to peak temperature Reflow times	8 minutes max. 3 times

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